



ALTERNATIVE TO PTO/SB/08a/b (07-05)

Substitute for form 1449/PTO				Complete if Known	
				Application Number	10/808,732
				Filing Date	March 24, 2004
				First Named Inventor	Hoang NGUYEN
				Art Unit	2828
				Examiner Name	A. Rodriguez
Sheet	1	of	1	Attorney Docket Number	509232001900

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (if known)			
AR	1.	US-2003/0007523-A1	01-09-2003	Chapman et al.	

FOREIGN PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Country Code ³ -Number ⁴ -Kind Code ⁵ (if known)			
AR	2.	EP-0 951 112-A	10-20-1999	Anritsu Corporation	T ⁶

*EXAMINER: Initial if information considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. ¹Applicant's unique citation designation number (optional). ²See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶Applicant is to place a check mark here if English language Translation is attached.

NON PATENT LITERATURE DOCUMENTS					
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.			T ²
AR	3.	Godard, A. et al. (April 2002). "Side-Mode Gain in Grating-Tuned Extended-Cavity Semiconductor Lasers: Investigation of Stable Single-Mode Operation Conditions," <i>IEEE Journal of Quantum Electronics</i> 38(4):390-401.			
AR	4.	Supplementary European Search Report mailed August 22, 2006, for EP Application No. 04758129.3, four pages.			
AR	5.	Wenz, H. et al. (February 1996). "Kontinuierlich Durchstimmbarer Halbleiterlaser Continuously Tunable Diode Laser," <i>Laser und Optoelektronik</i> 28(1):58-62 (Abstract and Extended Abstract in English.)			

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹Applicant's unique citation designation number (optional). ²Applicant is to place a check mark here if English language Translation is attached.

Examiner Signature pa-1106222	R. Rodriguez	Date Considered	1-25-07
----------------------------------	--------------	-----------------	---------